



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
30V	45mΩ @ V <sub>GS</sub> = 10V	4.0 A
300	$50m\Omega$ @ $V_{GS}$ = $4.5V$	3.5A

### **Description**

This new generation MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Load Switch
- DC-DC Converters
- Power management functions

### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

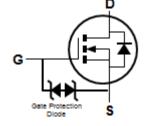
#### **Mechanical Data**

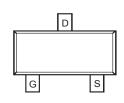
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)





SOT23





Top View

**Equivalent Circuit** 

Top View

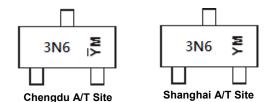
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN3053L-7	SOT23	3000/Tape & Reel
DMN3053L-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



3N6 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)

YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or  $\overline{Y}$  = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Year	2007	2008	2009	2010	201	1 20	)12	2013	2014	2015	2016	2017
Code	U	V	W	Х	Y		Z	Α	В	С	D	Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	$V_{DSS}$	30	V		
Gate-Source Voltage	V <sub>GSS</sub>	±12	V		
Continuous Drain Current (Note 6) $V_{GS}$ = 10V Steady $T_A$ = +25°C $T_A$ = +70°C			I <sub>D</sub>	4.0 3.5	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	35	Α		
Maximum Body Diode Forward Current (Note 6)	Is	1.5	Α		

## **Thermal Characteristics**

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	Б	0.76	W	
Total Fower Dissipation (Note 5)	T <sub>A</sub> = +70°C	$P_D$	0.48	v V	
Thermal Decistores, Junction to Ambient (Note 5)	Steady state	R <sub>0JA</sub>	165	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	R <sub>0JA</sub>	114	°C/W	
Total Dawar Dissination (Note 6)	T <sub>A</sub> = +25°C	Б	1.2	W	
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	$P_D$	0.8		
Thermal Desistance, Ityration to Austriant (Note C)	Steady state	$R_{\theta JA}$	100	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	69	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

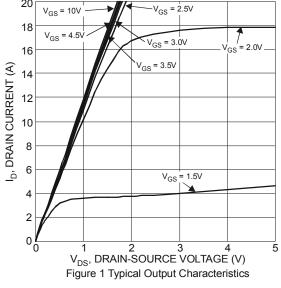
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_		>	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	1	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V
Gate-Body Leakage	I <sub>GSS</sub>		_	±10	μA	$V_{GS} = \pm 10V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.6	_	1.4	>	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
			36	45		$V_{GS} = 10V, I_D = 4.0A$
Static Drain-Source On-Resistance	Pro (ON)		38	50	mΩ	$V_{GS}$ = 4.5V, $I_{D}$ =3.5A
Static Drain-Source Off-Nesistance	R <sub>DS (ON)</sub>	_	42	53	11122	$V_{GS} = 3.0V, I_D = 3.0A$
			44	55		$V_{GS} = 2.5V, I_D = 2.8A$
Source-Drain Diode Forward Voltage	$V_{SD}$		0.7	1.2	٧	$V_{GS} = 0V, I_S = 1.25A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>		676		pF	
Output Capacitance	Coss		54		pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		42		pF	1.01/11/2
Gate Resistance	$R_g$		15.5	_	Ω	$V_{DS} = V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		7.3	_	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		17.2	_	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 4A
Gate-Source Charge	Q <sub>gs</sub>		1.2		nC	VDS - 15V, ID - 4A
Gate-Drain Charge	$Q_{gd}$		0.9	_	nC	
Turn-On Delay Time	t <sub>D(on)</sub>	_	2.0		ns	
Turn-On Rise Time	t <sub>r</sub>	_	5.5		ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V,
Turn-Off Delay Time	t <sub>D(off)</sub>		152		ns	$R_L = 15\Omega$ , $R_G = 6\Omega$
Turn-Off Fall Time	t <sub>f</sub>	_	32		ns	

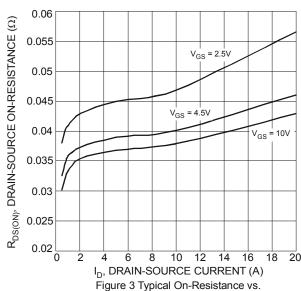
Notes:

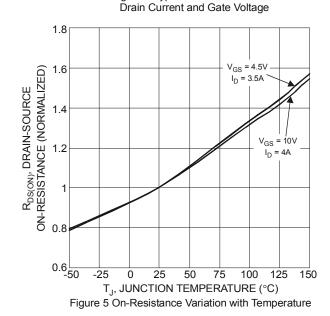
- 5. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
- 6. Device mounted on 1"x 1" FR-4 PCB with high coverage 2 oz. Copper, single sided.
  7. Short duration pulse test used to minimize self-heating effect.
  8. Guaranteed by design. Not subject to production testing.

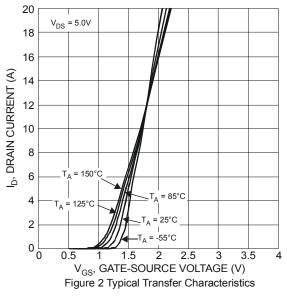
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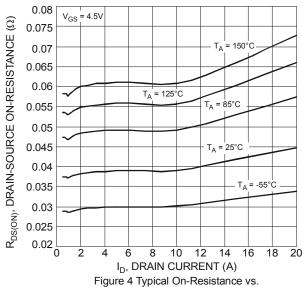


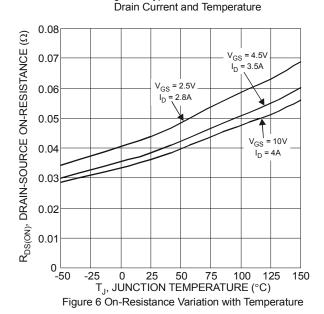














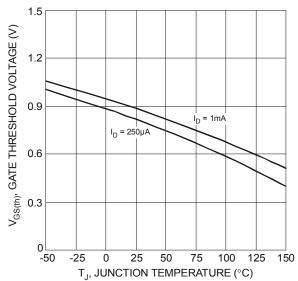
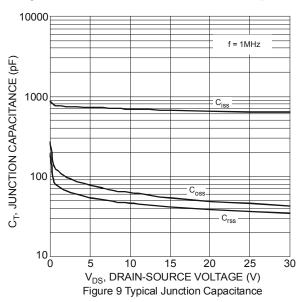
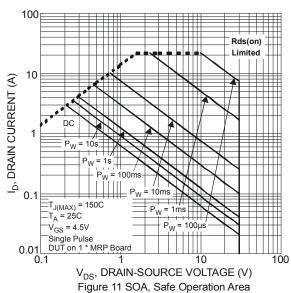
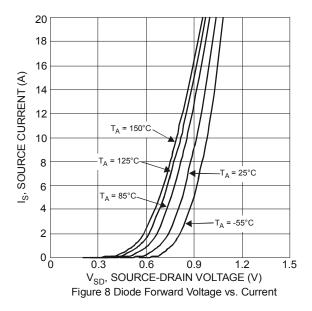
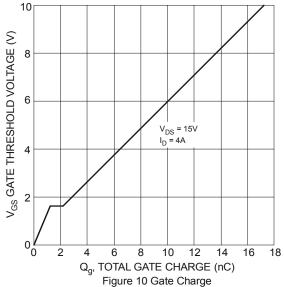


Figure 7 Gate Threshold Variation vs. Ambient Temperature

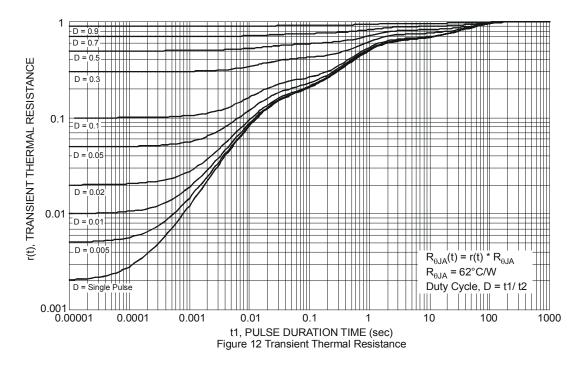






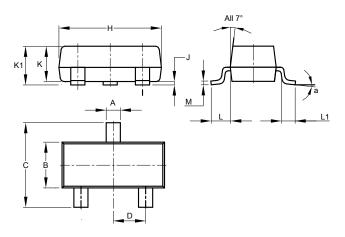






## **Package Outline Dimensions**

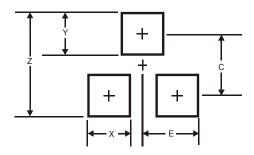
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
M	0.085	0.150	0.110					
а	8°							
All	All Dimensions in mm							

## **Suggested Pad Layout**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
С	2.0
E	1.35



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